

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSIII)

## SSM6N48FU

### Load Switching Applications

- 2.5-V drive
- N-ch 2-in-1
- Low ON-resistance:  $R_{DS(ON)} = 3.2 \Omega$  (max) (@ $V_{GS} = 4.0$  V)  
 $R_{DS(ON)} = 5.4 \Omega$  (max) (@ $V_{GS} = 2.5$  V)

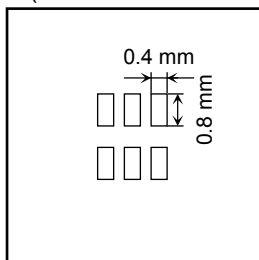
### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ ) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit
Drain-Source voltage		$V_{DSS}$	30	V
Gate-Source voltage		$V_{GSS}$	$\pm 20$	V
Drain current	DC	$I_D$	100	mA
	Pulse	$I_{DP}$	400	
Power dissipation		$P_D$ (Note 1)	300	mW
Channel temperature		$T_{ch}$	150	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-55 to 150	$^\circ\text{C}$

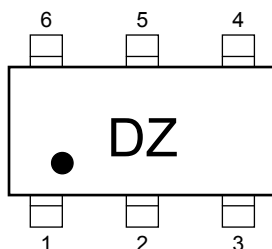
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

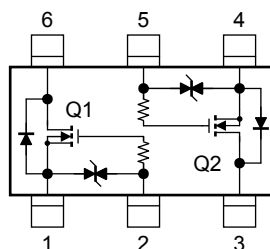
Note 1: Total rating  
 Mounted on an FR4 board  
 (25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm, Cu Pad: 0.32mm<sup>2</sup>  $\times$  6)



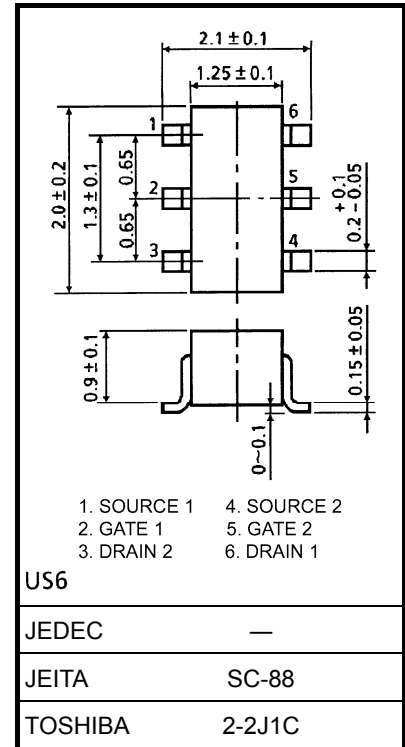
### Marking



### Equivalent Circuit (top view)



Unit: mm



Weight: 6.8 mg (typ.)

## Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

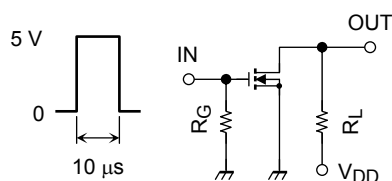
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = 0.1 \text{ mA}$ , $V_{GS} = 0 \text{ V}$	30	—	—	V
	$V_{(BR)DSX}$	$I_D = 0.1 \text{ mA}$ , $V_{GS} = -10 \text{ V}$ (Note 3)	16	—	—	
Drain cut-off current	$I_{DSS}$	$V_{DS} = 30 \text{ V}$ , $V_{GS} = 0 \text{ V}$	—	—	1	$\mu\text{A}$
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 12 \text{ V}$ , $V_{DS} = 0 \text{ V}$	—	—	$\pm 1$	$\mu\text{A}$
Gate threshold voltage	$V_{th}$	$V_{DS} = 3 \text{ V}$ , $I_D = 0.1 \text{ mA}$	0.8	—	1.5	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3 \text{ V}$ , $I_D = 10 \text{ mA}$ (Note 2)	33	—	—	mS
Drain-Source ON resistance	$R_{DS(ON)}$	$I_D = 10 \text{ mA}$ , $V_{GS} = 4 \text{ V}$ (Note 2)	—	2.0	3.2	$\Omega$
		$I_D = 10 \text{ mA}$ , $V_{GS} = 2.5 \text{ V}$ (Note 2)	—	3.0	5.4	
Input capacitance	$C_{iss}$	$V_{DS} = 3 \text{ V}$ , $V_{GS} = 0 \text{ V}$ , $f = 1 \text{ MHz}$	—	15.1	—	pF
Reverse transfer capacitance	$C_{rss}$		—	7.8	—	
Output capacitance	$C_{oss}$		—	12.4	—	
Switching time	Turn-on time	$V_{DD} = 5 \text{ V}$ , $I_D = 10 \text{ mA}$ , $V_{GS} = 0 \text{ to } 5 \text{ V}$ , $R_G = 50 \Omega$	—	35	—	ns
	Turn-off time		—	180	—	
Drain-source forward voltage	$V_{DSF}$	$I_D = -100 \text{ mA}$ , $V_{GS} = 0 \text{ V}$ (Note 2)	—	-0.83	-1.2	V

Note 2: Pulse test

Note 3: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

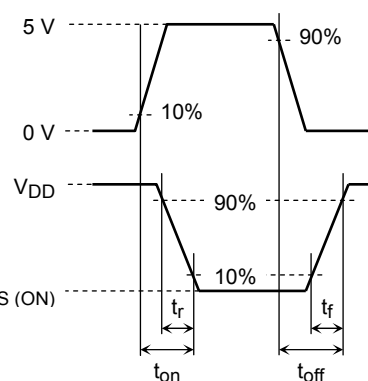
## Switching Time Test Circuit

### (a) Test circuit

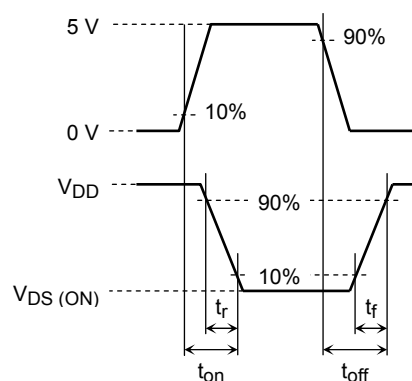


$V_{DD} = 5 \text{ V}$   
 $R_G = 50 \Omega$   
 Duty  $\leq 1\%$   
 $V_{IN}$ :  $t_r$ ,  $t_f < 5 \text{ ns}$   
 Common Source  
 $T_a = 25^\circ\text{C}$

### (b) $V_{IN}$



### (c) $V_{OUT}$



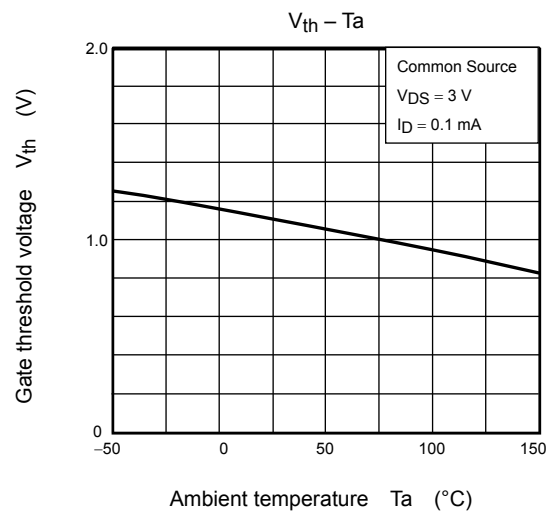
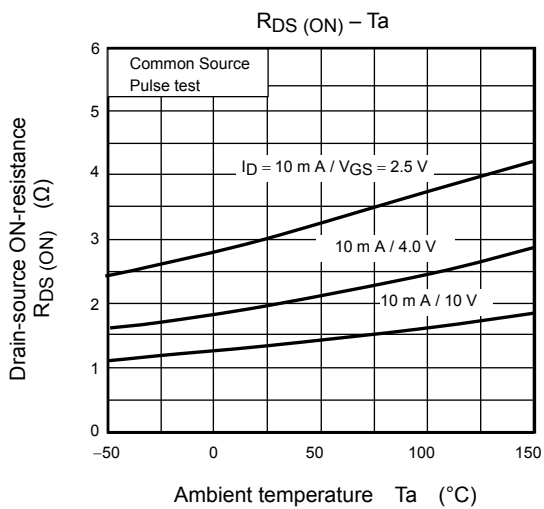
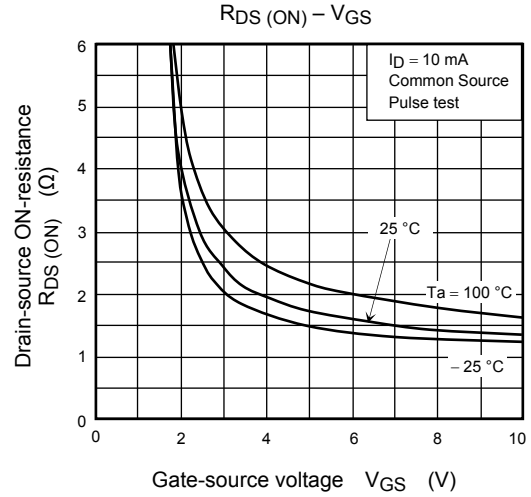
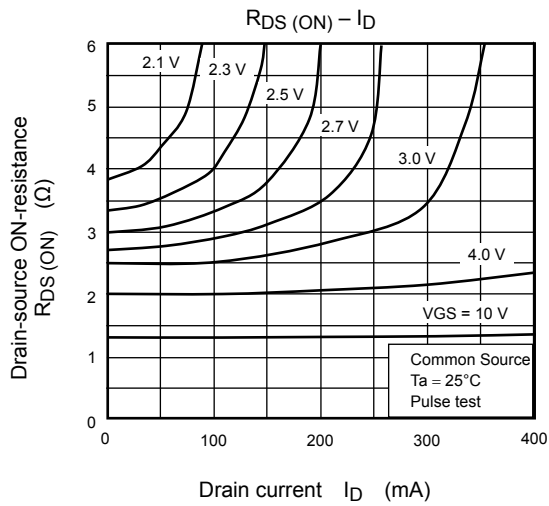
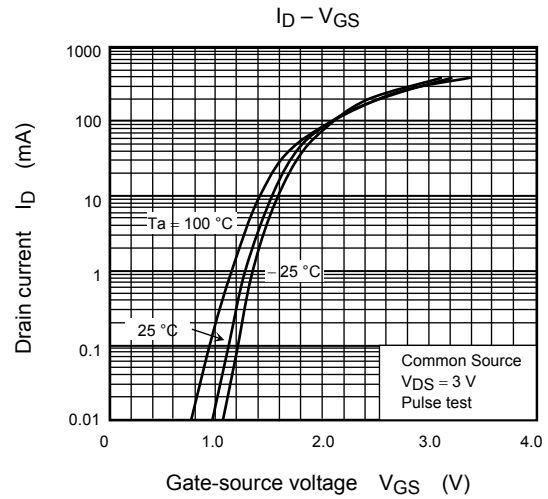
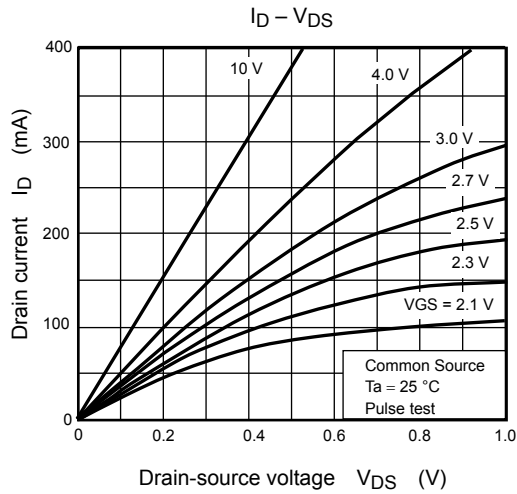
## Precaution

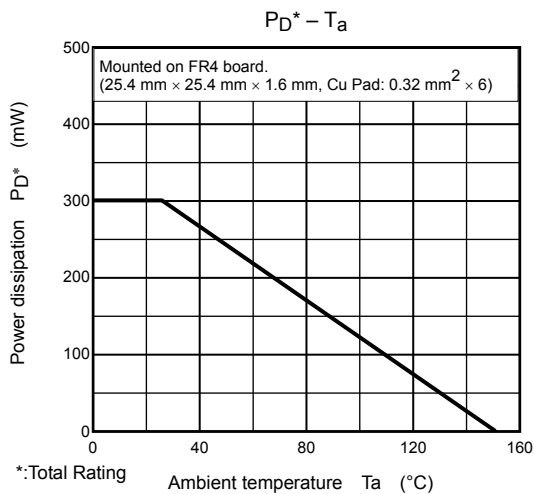
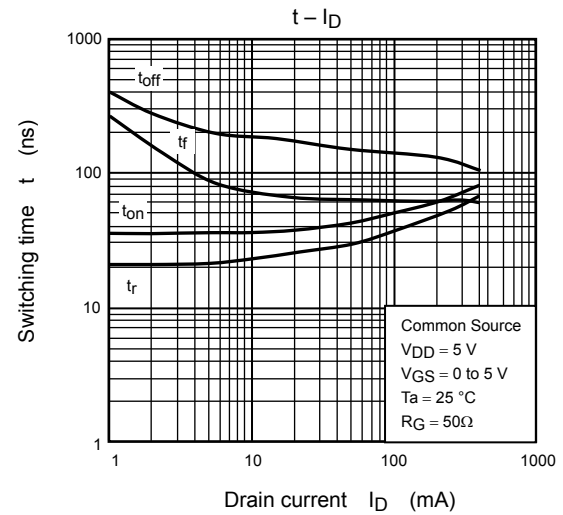
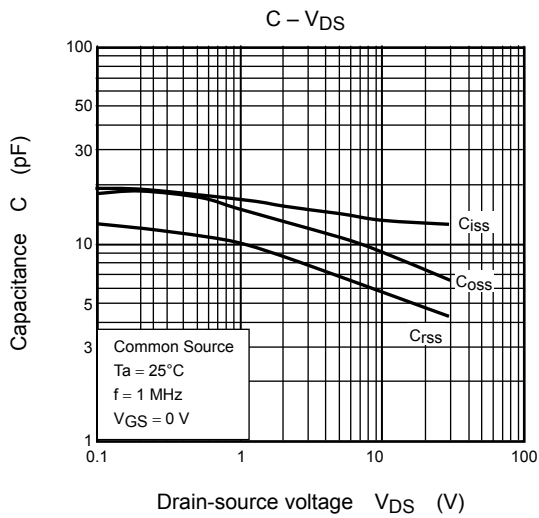
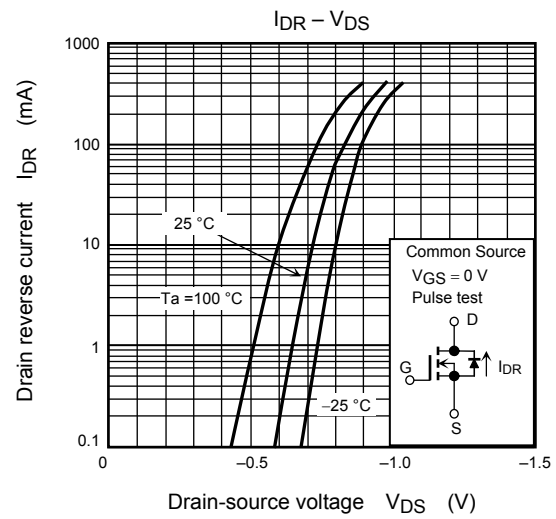
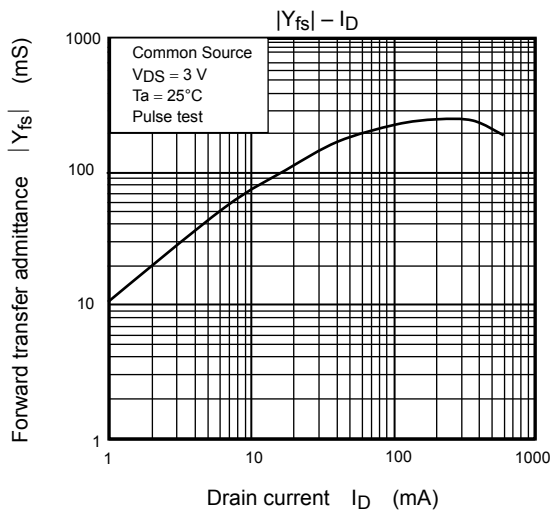
$V_{th}$  can be expressed as voltage between gate and source when low operating current value is  $I_D = 0.1 \text{ mA}$  for this product. For normal switching operation,  $V_{GS(ON)}$  requires higher voltage than  $V_{th}$  and  $V_{GS(OFF)}$  requires lower voltage than  $V_{th}$ . (Relationship can be established as follows:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ ) Please take this into consideration for using the device.

Do not use this device under avalanche mode. It may cause the device to break down.

## Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.





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